CMOS Digital Integrated Circuits Silicon Monolithic

74LCX125FT

1. Functional Description

• Low-Voltage Quad Bus Buffer with 5-V Tolerant Inputs and Outputs

2. General

The 74LCX125FT is a high-performance CMOS quad bus buffers. Designed for use in 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

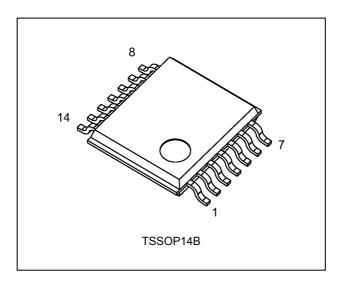
The device is designed for low-voltage (3.3 V) V_{CC} applications, but it could be used to interface to 5 V supply environment for inputs.

This device requires the 3-state control input \overline{OE} to be set high to place the output into the high impedance state. All inputs are equipped with protection circuits against static discharge.

3. Features

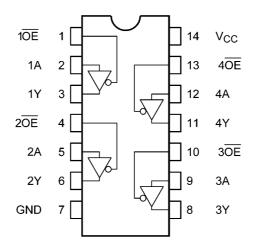
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: T_{opr} = -40 to 125 °C
- (3) Low-voltage operation: $V_{CC} = 1.65$ to 3.6 V
- (4) High-speed operation: $t_{pd} = 7.0 \text{ ns} (\text{max}) (V_{CC} = 3.3 \pm 0.3 \text{ V})$
- (5) Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$
- (6) Power-down protection provided on all inputs and outputs
- (7) Pin and function compatible with the 74 series(74LVC/ALVC/ etc.) 125 type
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

4. Packaging

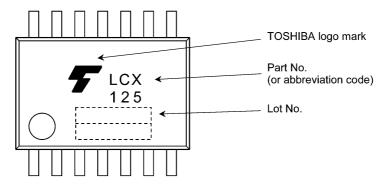


5. Pin Assignment

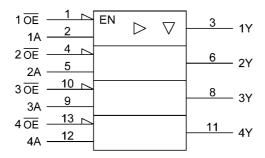
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6. Marking



7. IEC Logic Symbol



8. Truth Table

Inputs OE	Inputs A	Outputs Y
Н	Х	Z
L	L	L
L	Н	Н

X: Don't care

Z: High impedance

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 6.5	V
Input voltage	V _{IN}		-0.5 to 6.5	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 6.5	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	l _{IK}		-50	mA
Output diode current	I _{ОК}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	PD	(Note 4)	180	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Note 4: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		1.65 to 3.6	V
		(Note 1)	1.5 to 3.6	
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}	(Note 2)	0 to 5.5	V
		(Note 3)	0 to V _{CC}	
Output current	I _{OH} ,I _{OL}	(Note 4)	±24	mA
		(Note 5)	±12	
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv	(Note 6)	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Data retention only.

Note 2: Output in OFF state.

Note 3: High or low state

Note 4: V_{CC} = 3.0 to 3.6 V

Note 5: V_{CC} = 2.7 to 3.0 V

Note 6: V_{IN} = 0.8 to 2.0 V , V_{CC} = 3.0 V

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11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		1.65 to 2.3	$V_{CC} \times 0.9$	—	V
				2.3 to 2.7	1.7	_	
				2.7 to 3.6	2.0	—	
Low-level input voltage	V _{IL}	—		1.65 to 2.3		$V_{CC} \times 0.1$	V
				2.3 to 2.7		0.7	
				2.7 to 3.6	—	0.8	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.65 to 3.6	V _{CC} - 0.2	—	V
			I _{OH} = -4 mA	1.65	1.05	—	
			I _{OH} = -8 mA	2.3	1.7	—	
			I _{OH} = -12 mA	2.7	2.2	—	
			I _{OH} = -18 mA	3.0	2.4	—	
			I _{OH} = -24 mA	3.0	2.2	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.65 to 3.6	_	0.2	V
			I _{OL} = 4 mA	1.65	_	0.45	
			I _{OL} = 8 mA	2.3	—	0.7	
			I _{OL} = 12 mA	2.7		0.4	
			I _{OL} = 16 mA	3.0		0.4	
			I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current	I _{IN}	V _{IN} = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μA
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.65 to 3.6	—	±5.0	μA
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		1.65 to 3.6		10.0	μA
		V_{IN}/V_{OUT} = 3.6 to 5.5 V		1.65 to 3.6	—	±10.0	
Quiescent supply current	ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V (per 1 input)		2.7 to 3.6	—	500	μA

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditior	1	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		1.65 to 2.3	$V_{CC} \times 0.9$	—	V
				2.3 to 2.7	1.7	—	
				2.7 to 3.6	2.0	—	
Low-level input voltage	V _{IL}	—		1.65 to 2.3	—	$V_{CC} \times 0.1$	V
				2.3 to 2.7	—	0.7	
				2.7 to 3.6	—	0.8	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.65 to 3.6	V _{CC} - 0.2	_	V
			I _{OH} = -4 mA	1.65	0.9	—	
			I _{OH} = -8 mA	2.3	1.55	—	
			I _{OH} = -12 mA	2.7	2.0	_	
			I _{OH} = -18 mA	3.0	2.2	—	
			I _{OH} = -24 mA	3.0	2.0	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.65 to 3.6	—	0.2	V
			I _{OL} = 4 mA	1.65	—	0.65	
			I _{OL} = 8 mA	2.3	—	0.9	
			I _{OL} = 12 mA	2.7	—	0.6	
			I _{OL} = 16 mA	3.0	—	0.6	
			I _{OL} = 24 mA	3.0	—	0.75	
Input leakage current	I _{IN}	V _{IN} = 0 to 5.5 V		1.65 to 3.6	—	±20.0	μA
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 3.6	—	±20.0	μA
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	—	40.0	μA
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		1.65 to 3.6	_	40.0	μA
		V _{IN} /V _{OUT} = 3.6 to 5.5 V		1.65 to 3.6	_	±40.0	
Quiescent supply current	Δl _{CC}	V _{IH} = V _{CC} - 0.6 V (per 1 input)		2.7 to 3.6	—	5.0	mA

11.3. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	20.0	ns
			Table 11.7.1, Fig. 11.8.1, Table 11.8.1	2.5 ± 0.2	_	7.5	
				2.7		6.5	
				3.3 ± 0.3	1.5	6.0	
3-state output enable time	t _{PZL} ,t _{PZH}		See 11.7 AC Test Circuit,		_	30.0	ns
			Table 11.7.1, Fig. 11.8.2, Table 11.8.1	2.5 ± 0.2	_	15.0	
				2.7	_	8.0	
				3.3 ± 0.3	1.5	7.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		See 11.7 AC Test Circuit,	1.8 ± 0.15		28.0	ns
			Table 11.7.1, Fig. 11.8.2, Table 11.8.1	2.5 ± 0.2	_	14.0	
			Fig. 11.0.2, Table 11.0.1	2.7	_	7.0	
				$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.0	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.7	_	_	ns
				$\textbf{3.3}\pm\textbf{0.3}$	-	1.0	

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

11.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	22.0	ns
			Table 11.7.1, Fig. 11.8.1, Table 11.8.1	2.5 ± 0.2	_	8.5	
			Fig. 11.0.1, Table 11.0.1	2.7	_	7.5	
				3.3 ± 0.3	1.5	7.0	
3-state output enable time	t _{PZL} ,t _{PZH}		See 11.7 AC Test Circuit,			33.0	ns
			Table 11.7.1, Fig. 11.8.2, Table 11.8.1	2.5 ± 0.2	_	16.5	
				2.7	_	9.0	
				3.3 ± 0.3	1.5	8.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	31.0	ns
			Table 11.7.1,	2.5 ± 0.2	_	15.5	
	Fig. 11.8.2, Table 11.8.1		2.7	_	8.0		
				3.3 ± 0.3	1.5	7.0	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.7	_	_	ns
				3.3 ± 0.3		1.0	

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

11.5. Dynamic Switching Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

11.6. Capacitive Characteristics (Unless otherwise specified, Ta = 25 °C)

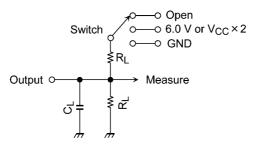
Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}			3.3	7	pF
Output capacitance	C _{OUT}			3.3	8	pF
Power dissipation capacitance	C _{PD}	(Note 1)	f _{IN} = 10 MHz	3.3	25	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4 \text{ (per 1 gate)}$

11.7. AC Test Circuit

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Parameter	Switch	Test Condition
t _{PLH} , t _{PHL}	OPEN	_
t _{PLZ} , t _{PZL}	6.0 V	V_{CC} = 3.3 \pm 0.3 V
		V _{CC} = 2.7 V
	$V_{CC} \times 2$	V_{CC} = 2.5 \pm 0.2 V
		V_{CC} = 1.8 \pm 0.15 V
t _{PHZ} , t _{PZH}	GND	—

Table 11.7.1	Parameter for AC	Test Circuit
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11.8. AC Waveform

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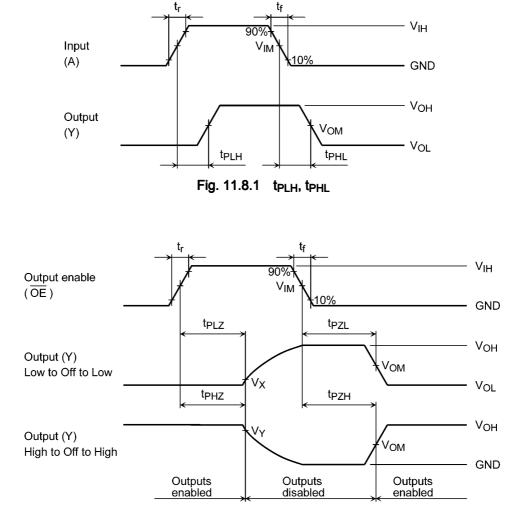


Fig. 11.8.2 tpLz, tpHz, tpZL, tpZH

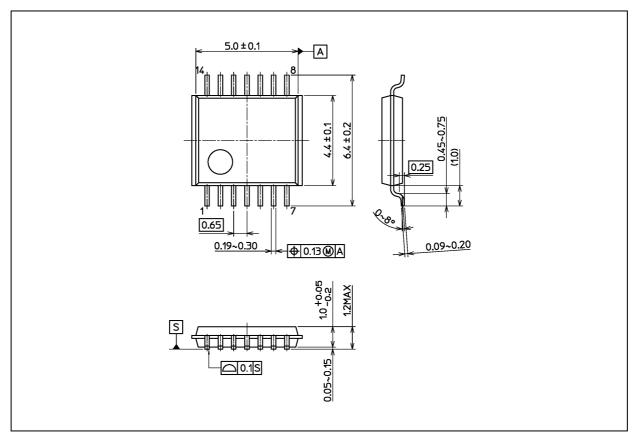
	Table 11.8.1 AC Waveform Symbols									
	Symbol	V_{CC} = 3.3 ± 0.3 V V_{CC} = 2.7 V	V_{CC} = 2.5 \pm 0.2 V	V_{CC} = 1.8 \pm 0.15 V						
Input	V _{IH}	2.7 V	V _{CC}	V _{CC}						
	V _{IM}	1.5 V	V _{CC} /2	V _{CC} /2						
	t _r , t _f	2.5 ns	2.0 ns	2.0 ns						
Output	V _{OM}	1.5 V	V _{OH} /2	V _{OH} /2						
	V _X	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V						
	V _Y	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V						
Load	CL	50 pF	30 pF	30 pF						
	RL	500 Ω	500 Ω	1 kΩ						



74LCX125FT

Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)	
Nickname: TSSOP14B	

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